

POWER MANAGEMENT

Absolute Maximum Ratings

Exceeding the specifications below may result in permanent damage to the device, or device malfunction. Operation outside of the parameters specified in the Electrical Characteristics section is not implied.

Parameter	Symbol	Max	Units
V _{in} , EN, V _o , ADJ to GND		7	V
Power Dissipation	P _D	Internally Limited	W
Thermal Resistance Junction to Ambient ⁽¹⁾	θ _{JA}	36	°C/W
Thermal Resistance Junction to Case ⁽¹⁾	θ _{JC}	5.5	°C/W
Operating Ambient Temperature Range	T _A	-40 to +85	°C
Operating Junction Temperature Range	T _J	-40 to +125	°C
Storage Temperature Range	T _{STG}	-65 to +150	°C
Peak IR Reflow Temperature (10s to 30s)	T _P	260	°C
ESD Rating (Human Body Model) ⁽²⁾	V _{ESD}	2	kV

Notes:

(1) Calculated from package in still air, mounted to 3" x 4.5", 4 layer FR4 PCB with thermal vias under the exposed pad per JESD51 standards,

(2) Tested according to JEDEC standard JESD22-A114-B.

Electrical Characteristics

Unless specified: V_{EN} = V_{IN}, V_{IN} = 1.6V to 5.5V, I_O = 10μA to 2A.

Values in **bold** apply over the full operating temperature range.

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
VIN						
Supply Voltage Range	V _{IN}		1.6		5.5	V
Quiescent Current	I _Q	V _{IN} = 3.3V		0.75	1.75	mA
		V _{IN} = 5.5V, V _{EN} = 0V		10	50	μA
VO						
Output Voltage ⁽¹⁾	V _O	V _{IN} = V _O + 0.5V, I _O = 10mA	-2%	V _O	+2%	V
(Fixed Voltage, V _{ADJ} = 0)		1.60V ≤ V _{IN} ≤ 5.5V, I _O = 10mA	-3%		+3%	
Line Regulation ⁽¹⁾	REG _(LINE)	I _O = 10mA		0.2	0.4	%/V
Load Regulation ⁽¹⁾	REG _(LOAD)	I _O = 10mA to 2A		0.5	1.0	%
Dropout Voltage ⁽¹⁾⁽²⁾	V _{DO}	I _O = 1A		90	300	mV
					400	
		I _O = 1.5A		200	400	mV
					500	

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Electrical Characteristics (Cont.)

Unless specified: $V_{EN} = V_{IN}$, $V_{IN} = 1.6V$ to $5.5V$, $I_O = 10\mu A$ to $2A$.
Values in **bold** apply over the full operating temperature range.

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
VO (Cont.)						
Dropout Voltage ⁽¹⁾⁽²⁾	V _{DO}	I _O = 2A, V _{IN} = V _O + 0.5V		300	500	mV
		I _O = 2A, V _{IN} = V _O + 0.6V			600	
Minimum Load Current ⁽³⁾	I _O	V _{IN} = V _O + 0.5V		1	10	μA
Current Limit	I _{CL}		2.2	3	4.5	A
ADJ						
Reference Voltage ⁽¹⁾	V _{REF}	V _{IN} = 3.3V, V _{ADJ} = V _{OUT} , I _O = 10mA	0.792	0.8	0.808	V
			0.784		0.816	
Adjust Pin Current ⁽⁴⁾	I _{ADJ}	V _{ADJ} = V _{REF}		80	200	nA
Adjust Pin Threshold ⁽⁵⁾	V _{TH(ADJ)}		0.05	0.16	0.40	V
EN						
Enable Pin Current	I _{EN}	V _{EN} = 0V, V _{IN} = 3.3V		1.5	10	μA
Enable Pin Threshold	V _{IH}	V _{IN} = 3.3V	1.6			V
	V _{IL}	V _{IN} = 3.3V			0.4	
Over Temperature Protection						
High Trip level	T _{HI}			160		°C
Hysteresis	T _{HYST}			10		°C

Notes:

(1) Low duty cycle pulse testing with Kelvin connections required.

(2) $V_{DO} = V_{IN} - V_O$ when V_O decreases by 1.5% of its nominal output voltage with $V_{IN} = V_O + 0.8V$

(3) Required to maintain regulation. Voltage set resistors R1 and R2 are usually utilized to meet this requirement. Adjustable versions only.

(4) Guaranteed by design.

(5) When V_{ADJ} exceeds this threshold, the "Sense Select" switch disconnects the internal feedback chain from the error amplifier and connects V_{ADJ} instead.

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Ordering Information

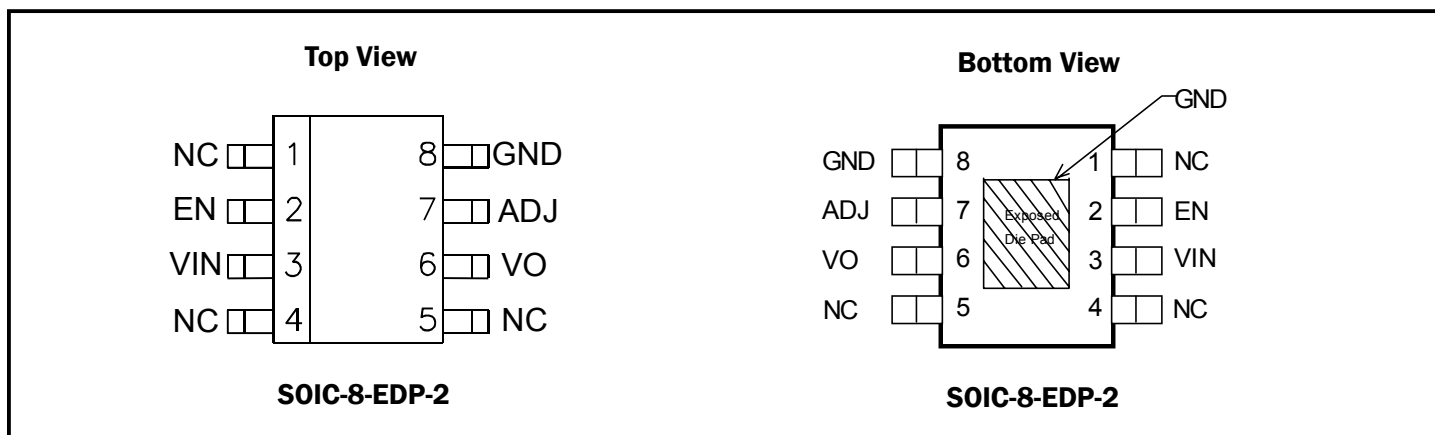
Part Number	Package	Temp. Range (T _j)
SC4215ISTR ⁽¹⁾	SOIC-8-EDP-2	-40 to +125°C
SC4215ISTR ^{T(1)(2)}		
SC4215EVB	Evaluation Board	

Notes:

(1) Only available in tape and reel packaging. A reel contains 2500 devices.

(2) Lead-free product. This product is fully WEEE and RoHS compliant.

Pin Configuration

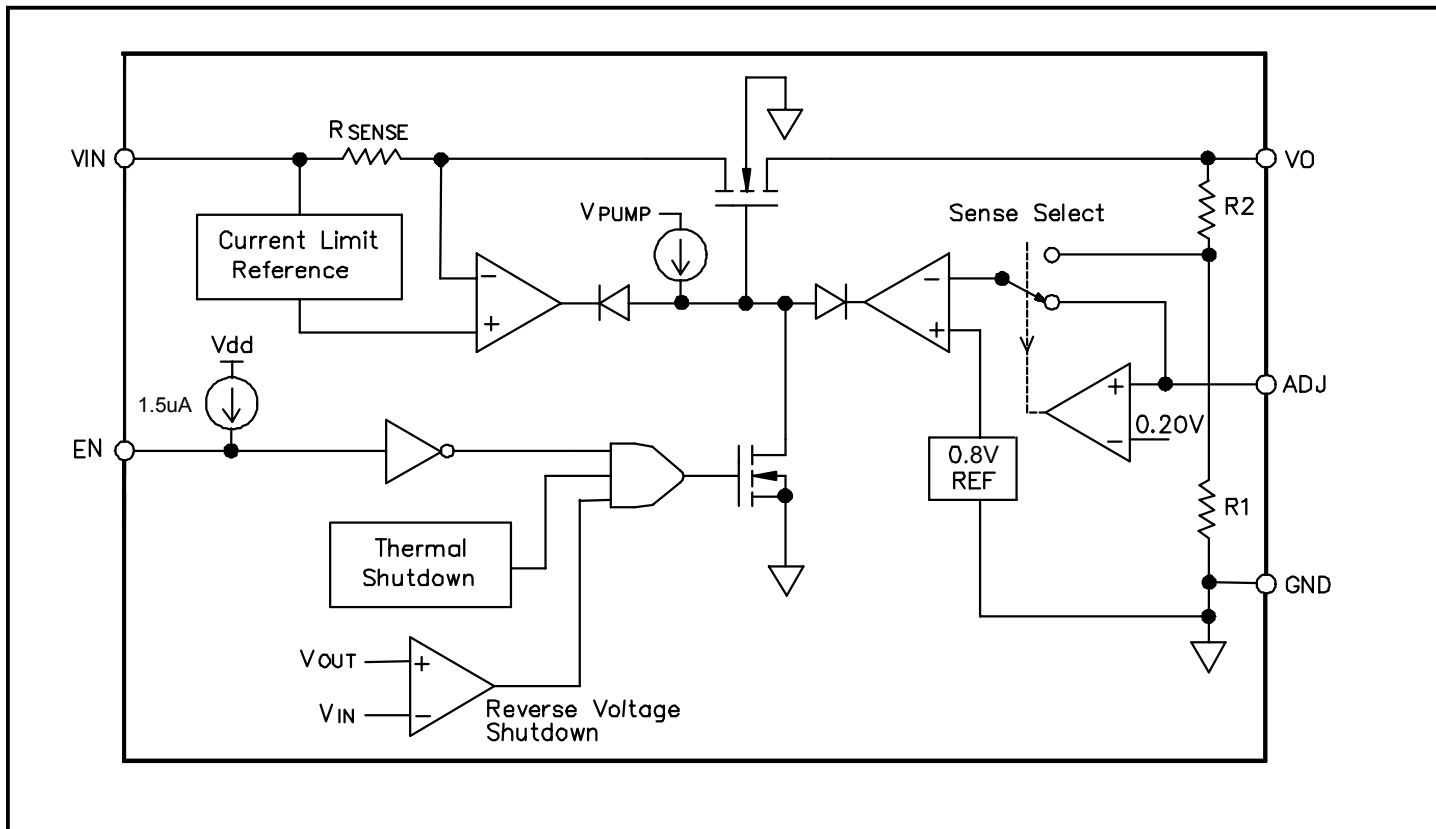


Pin Descriptions

Pin #	Pin Name	Pin Description
2	EN	Enable Input. Pulling this pin below 0.4V turns the regulator off, reducing the quiescent current to a fraction of its operating value. The device will be enabled if this pin is left open. Connect to VIN if not being used.
3	VIN	Input voltage. For regulation at full load, the input to this pin must be between (VO+ 0.5V) and 5.5V. Minimum VIN = 1.6V. A large bulk capacitance should be placed closely to this pin to ensure that the input supply does not sag below 1.6V. Also a minimum of 4.7uF ceramic capacitor should be placed directly at this pin.
6	VO	The pin is the power output of the device. A minimum of 10uF capacitor should be placed directly at this pin.
7	ADJ	When this pin is grounded, an internal resistor divider sets the output voltage to 2.5V. If connected to the Vo pin, the output voltage will be set at 0.8V. If external feedback resistors are used, the output voltage will be (See Application Circuits on page 1): $VO = \frac{0.8 (R1 + R2)}{R2} \text{ Volts}$
8	GND	Reference ground. The GND pin and the exposed die pad must be connected together at the IC pin.
1,4,5	NC	No Connection.
	THERMAL PAD	Pad for heatsinking purposes. Connect to ground plane using multiple vias. Not electrically connected internally.

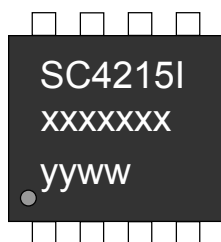
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Block Diagram



Marking Information

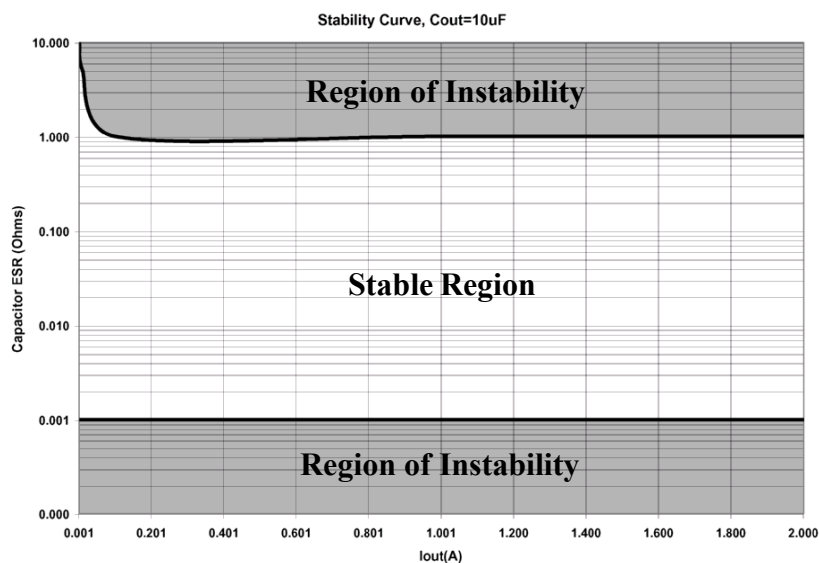
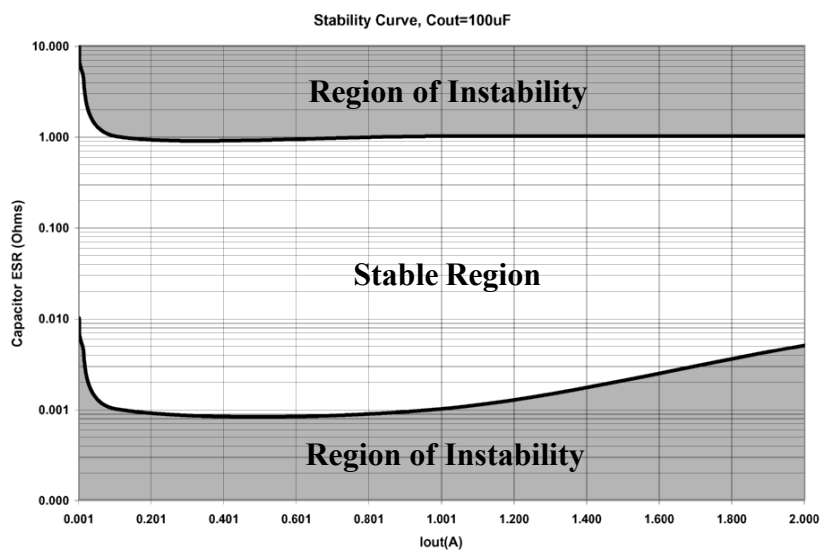
Top View



yyww = Datecode (Example: 0015)
xxxxxxx = Semtech Lot No. (Example: 00101)

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Typical Characteristics



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Applications Information

Introduction

The SC4215 is intended for applications where high current capability and very low dropout voltage are required. It provides a very simple, low cost solution that uses very little pcb real estate. Additional features include an enable pin to allow for a very low power consumption standby mode, and a fully adjustable output.

Component Selection

Input capacitor: A minimum of 4.7µF ceramic capacitor is recommended to be placed directly next to the Vin pin. This allows for the device being some distance from any bulk capacitance on the rail. Additionally, bulk capacitance of about $\geq 10\mu\text{F/A}$ (output load) may be added closely to the input supply pin of the SC4215 to ensure that Vin does not sag, improving load transient response.

Output capacitor: A minimum bulk capacitance of $\geq 10\mu\text{F/A}$ (output load), along with a 0.1µF ceramic decoupling capacitor is recommended. Increasing the bulk capacitance will improve the overall transient response. The use of multiple lower value ceramic capacitors in parallel to achieve the desired bulk capacitance will not cause stability issues. Although designed for use with ceramic output capacitors, the SC4215 is extremely tolerant of output capacitor ESR values and thus will also work comfortably with tantalum output capacitors.

Noise immunity: In very electrically noisy environments, it is recommended that 0.1µF ceramic capacitors be placed from IN to GND and OUT to GND as close to the device pins as possible.

Internal voltage selection: By connecting the ADJ pin to GND, an internal resistor divider will regulate the output voltage to 2.5V. If the ADJ pin is connected directly to the VO pin, the output voltage will be regulated to the 0.8V internal reference.

External voltage selection resistors: The use of 1% resistors, and designing for a current flow $\geq 10\mu\text{A}$ is recommended to ensure a well regulated output (thus $R2 \leq 50\text{k}\Omega$).

Enable: Pulling this pin below 0.4V turns the regulator off, reducing the quiescent current to a fraction of its operating value. A pull up resistor up to 400kOhms should be connected from this pin to the VIN pin in application where supply voltages of $V_{in} < 1.9\text{V}$ are required. For applications with higher voltages than 1.9V, EN pin could be left open or connected to VIN.

Thermal Considerations

The power dissipation in the SC4215 is approximately equal to the product of the output current and the input to output voltage differential:

$$P_D \approx (V_{IN} - V_{OUT}) \cdot I_O$$

The absolute worst-case dissipation is given by:

$$P_{D(MAX)} = (V_{IN(MAX)} - V_{OUT(MIN)}) \cdot I_{O(MAX)} + V_{IN(MAX)} \cdot I_{Q(MAX)}$$

For a typical scenario, $V_{IN} = 3.3\text{V} \pm 5\%$, $V_{OUT} = 2.8\text{V}$ and $I_O = 1.5\text{A}$, therefore:

$$V_{IN(MAX)} = 3.465\text{V}, V_{OUT(MIN)} = 2.744\text{V} \text{ and } I_{Q(MAX)} = 1.75\text{mA},$$

$$\text{Thus } P_{D(MAX)} = 1.09\text{W}.$$

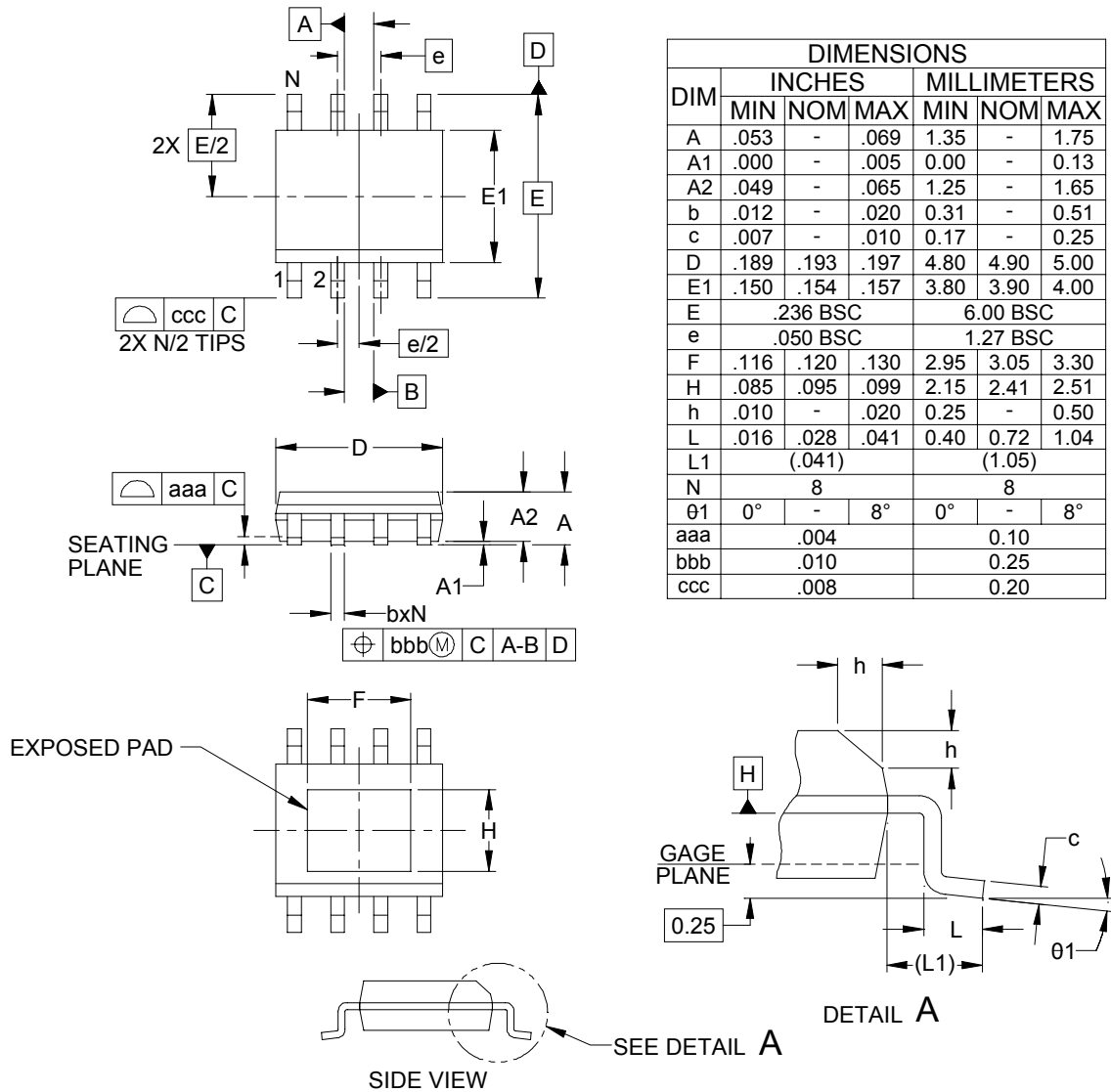
Using this figure, and assuming $T_{A(MAX)} = 70^\circ\text{C}$, we can calculate the maximum thermal impedance allowable to maintain $T_J \leq 150^\circ\text{C}$:

$$R_{TH(J-A)(MAX)} = \frac{(T_{J(MAX)} - T_{A(MAX)})}{P_{D(MAX)}} = \frac{(150 - 70)}{1.09} = 73.4^\circ\text{C} / \text{W}$$

This should be achievable for the SOIC-8EDP package using pcb copper area to aid in conducting the heat away, such as one square inch of copper connected to the exposed die pad of the device. Internal ground/power planes and air flow will also assist in removing heat. For higher ambient temperatures it may be necessary to use additional copper area.

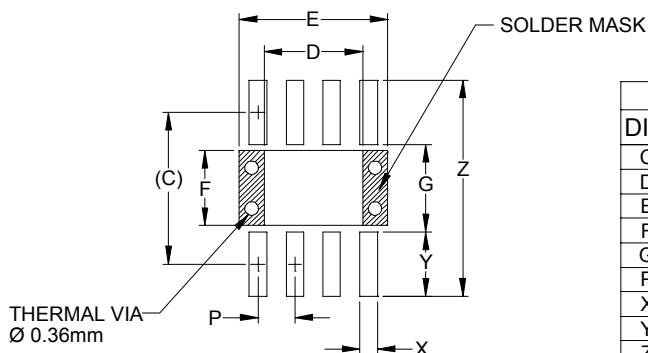
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Outline Drawing - SOIC-8-EDP-2



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Land Pattern - SOIC-8-EDP-2



DIMENSIONS		
DIM	INCHES	MILLIMETERS
C	(.205)	(5.20)
D	.134	3.40
E	.201	5.10
F	.101	2.56
G	.118	3.00
P	.050	1.27
X	.024	0.60
Y	.087	2.20
Z	.291	7.40

NOTES:

1. THIS LAND PATTERN IS FOR REFERENCE PURPOSES ONLY. CONSULT YOUR MANUFACTURING GROUP TO ENSURE YOUR COMPANY'S MANUFACTURING GUIDELINES ARE MET.
2. REFERENCE IPC-SM-782A, RLP NO. 300A.
3. THERMAL VIAS IN THE LAND PATTERN OF THE EXPOSED PAD SHALL BE CONNECTED TO A SYSTEM GROUND PLANE. FAILURE TO DO SO MAY COMPROMISE THE THERMAL AND/OR FUNCTIONAL PERFORMANCE OF THE DEVICE.

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